

2SC1515(K)

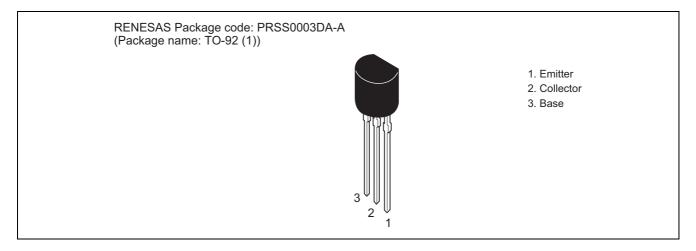
Silicon NPN Triple Diffused

REJ03G0689-0200 (Previous ADE-208-1055) Rev.2.00 Aug.10.2005

Application

High voltage switching

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

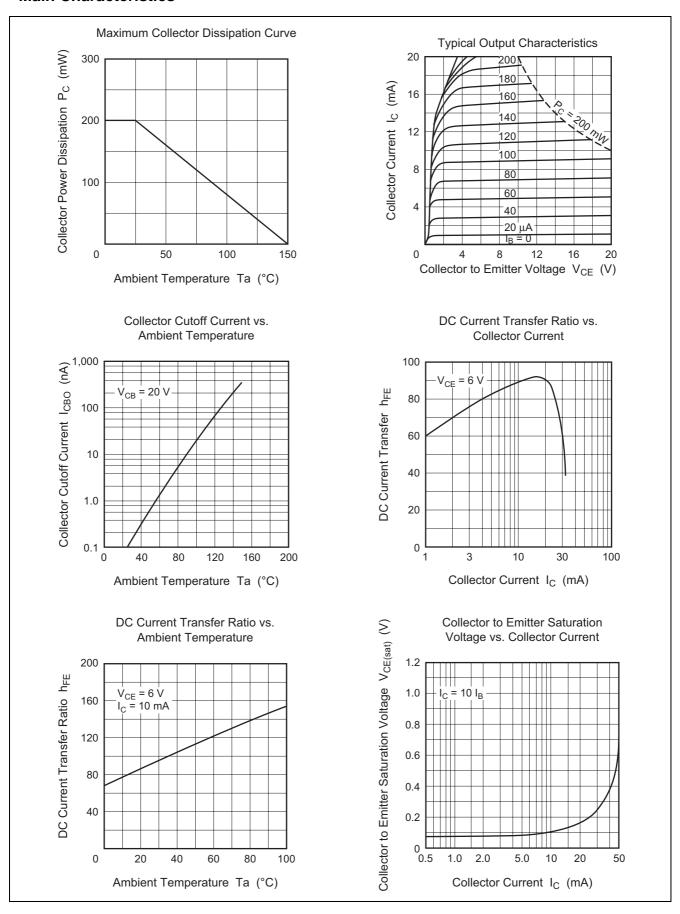
Item	Symbol	Ratings	Unit
Collector to base voltage	V _{CBO}	200	V
Collector to emitter voltage	V _{CES}	200	V
	V _{CEO}	150	V
Emitter to base voltage	V _{EBO}	5	V
Collector current	Ic	50	mA
Collector power dissipation	Pc	200	mW
Junction temperature	Tj	150	°C
Storage temperature	Tstg	-55 to +150	°C

Electrical Characteristics

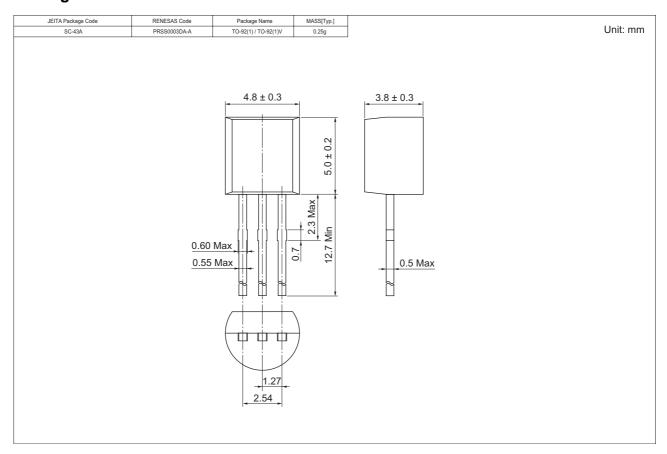
 $(Ta = 25^{\circ}C)$

Item	Symbol	Min	Тур	Max	Unit	Test conditions
Collector to emitter breakdown voltage	$V_{(BR)CES}$	200	_	_	V	$I_C = 10 \ \mu A, \ R_{BE} = 0$
	V _{(BR)CEO}	150	_	_	V	$I_C = 1 \text{ mA}, R_{BE} = \infty$
Emitter to base breakdown voltage	$V_{(BR)EBO}$	5	_	_	V	$I_E = 10 \mu A, I_C = 0$
Collector cutoff current	I _{CBO}	_	_	0.1	μΑ	$V_{CB} = 20 \text{ V}, I_E = 0$
DC current transfer ratio	h _{FE}	30	_	300		$V_{CE} = 6 \text{ V}, I_{C} = 10 \text{ mA}$
Collector to emitter saturation voltage	V _{CE(sat)}	_	_	1.0	V	$I_C = 10 \text{ mA}, I_B = 1 \text{ mA}$
Base to emitter saturation voltage	V _{BE(sat)}	_	_	1.5	V	$I_C = 10 \text{ mA}, I_B = 1 \text{ mA}$
Gain bandwidth product	f⊤	60	_	_	MHz	$V_{CE} = 6 \text{ V}, I_{C} = 10 \text{ mA}$
Collector output capacitance	Cob		_	10	pF	$V_{CB} = 6 \text{ V}, I_{E} = 0, f = 1 \text{ MHz}$

Main Characteristics



Package Dimensions



Ordering Information

Part Name	Quantity	Shipping Container
2SC1515KTZ	2500	Hold Box, Radial Taping

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